OPB750N, OPB750T OPB755NZ, OPB755TZ, OPB755TAZ

Features:

- High contrast ratio (1,000 :1 minimum)
- Low cost plastic housing
- PCBoard mount (OPB750N, OPB750T)
- 12" (305 mm) 26 AWG wires (OPB755NZ, OPB755TZ)
- Available with no-mounting tabs "N" package
- Available with two mounting tabs "T" package

Description:

Each sensor in the **OPB750** and **OPB755** series has a reflective assembly that features a Light Emitting Diode (LED) and phototransistor output designed to decrease low-level light, while not affecting the high-level light gain.

The **OPB750N** and **OPB750T** devices have are designed for PCBoard mounting with 0.40" (10 mm) length leads. **OPB755NZ**, **OPB755TZ** and **OPB755TAZ** assemblies are designed for remote mounting. The **OPB755NZ** and **OPB755TZ** have 12" (305 mm) UL rated wire, 26 AWG wire leads that terminate into an AMP # 3-640442-5 connector. The **OPB755TAZ** has 24" (610 mm) UL rated wire, 26 AWG leads. The **OPB750T**, **OPB755TZ** and **OPB755TAZ** have two mounting tabs while the **OPB750N** and **OPB755NZ** have no mounting tabs.

Photologic[®] output versions are available with the **OPB760** and **OPB770** series.

Custom electrical, wire and cabling and connectors are available. Contact your local **Ordering Information** representative or OPTEK for more LED Peak **Reflection Distance** Part Lead Length information. Number Wavelength Tabs Sensor Inch 0.080" (2.03 mm) **Applications:** OPB750N 0.150" (3.81 mm) No tabs • Non-contact reflective object sensor 0.220" (5.59 mm) Transistor 0.40" 890 nm & Rbe Assembly line automation 0.080" (2.03 mm) Machine automation 0.150" (3.81 mm) OPB750T 2 Tabs Machine safety 0.220" (5.59 mm) • End of travel sensor 0.080" (2.03 mm) Door sensor OPB755N7 0.150" (3.81 mm) No tabs 12" / 26 0.220" (5.59 mm) AWG Wire 0.080" (2.03 mm) with connector Transistor OPB755TZ 0.150" (3.81 mm) 890 nm & Rbe 0.220" (5.59 mm) 2 Tabs 0.080" (2.03 mm) 24" / 26 AWG Wire OPB755TAZ 0.150" (3.81 mm) NO 0.220" (5.59 mm) connector



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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Absolute	• Maximum Ratings (T _A = 25° C unless c	otherwise	noted))				
Operating and Storage Temperature Range OPB750N, OPB750T OPB755NZ, OPB755TZ, OPB755TAZ							-40° C to + 85° C -40° C to + 80° C	
Lead Soldering Temperature ⁽¹⁾							260° C	
Input Dio	de						l	
Forward DC Current							50 mA	
Peak Forward Current (1 μ pulse width, 300 pps)							1 A	
Reverse DC Voltage							2 V	
Power Dissipation							100 mW	
Output Pl	nototransistor						1	
Collector-Emitter Voltage						24 V		
Collector DC Current						30 V		
Power Dissipation ⁽³⁾							100 mW	
Electrica	I Characteristics ($T_A = 25^\circ$ C unless other	rwise no	ted)				1	
SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS		
Input Dioc	le (See OP240 for additional information)					1		
V _F	Forward Voltage	-	-	1.8	V	I _F = 40 mA		
I _R	Reverse Current	-	-	100	μA	V _R = 2 V		
Output Ph	ototransistor (see OP550 for additional inform	nation)			1			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	24	-	-	V	I _c = 100 μA		
I _{CEO}	Collector Dark Current	-	-	100	nA	V _{CE} = 10 V, I _F = 0, H = 0		
Coupled					-	1		
V _{CE(SAT)}	Saturation Voltage	-	-	.40	V	I_{c} = 150 µA, I_{F} = 30 mA, d = 0.22"		
I _{C(OFF)}	Off-State Collector Current ⁽⁵⁾	-	-	250	nA	I _F = 30 mA, V _{CE} = 5 V d = 0.08", 0.15", 0.22"		
I _{C(ON)}	On-State Collector Current ⁽⁴⁾	500 375 250	- - -		μΑ	$I_{F} = 30 \text{ mA}, V_{CE} = 5 \text{ V}, d = 0.08''$ $I_{F} = 30 \text{ mA}, V_{CE} = 5 \text{ V}, d = 0.15''$ $I_{F} = 30 \text{ mA}, V_{CE} = 5 \text{ V}, d = 0.22''$		

Notes:

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

(2) Derate linearly 1.67 mW/° C above 25° C.

(3) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.

(4) Photocurrent is measured using an Eastman Kodak neutral white test card having 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog #E 152 7795.

(5) IC_(OFF) is the photocurrent measured with current to the input diode and a 5% reflecting surface.

(6) All parameters tested using pulse techniques.

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Normalized at I_F=20mA, 20°C, Kodak 90% at 0.150"

Kodak 90%

Kodak 19% Corporate - Avery

Performance



Collector Current vs. Object Distance

0.20

0.30

0.40

0.50

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